NSN 5961-01-089-0780

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-089-0780 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-39 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 drain to source voltage and 90.0 drain to gate voltage and 30.0 forward gate to source voltage and 30.0 reverse gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes source cutoff current of standard range **Power Rating Per Characteristic:** 8.3 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No